## AMT1806-1 12 - 18GHz Power Divider Chip



#### **Key Features:**

Frequency range: 12 – 18GHz
Input/output standing wave: 1.4

Insertion loss: 1.4dBIsolation: 30dB

• Chip dimensions: 1.7mm x 1.05mm x 0.1mm

• Applications: wireless communication, transceiver module, radio telecommunication etc.

### **Description:**

AMT1806-1 is a 1-to-4 power divider chip designed by Gallium Arsenide (GaAs) process, it covers 12 – 18GHz frequency range, with typical 30dB isolation. This chip is designed with ground through metal vias on the back technology.

#### Absolute Maximum Ratings (Ta = 25°C)

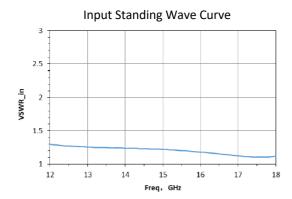
Symbol	Parameter	Value	Remark	
Pin	Input Power	+37dBm		
Tch	Operating Temperature	150°C		
Tm	Sintering Temperature	310°C	30s, N <sub>2</sub> protection	
Tstg	Storage Temperature	-65 ~ +150°C		

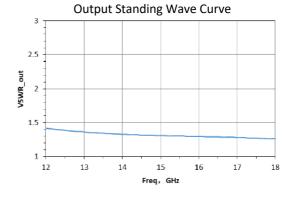
<sup>[1]</sup> Operation outside any of the Absolute Maximum Ratings may cause permanent device damage.

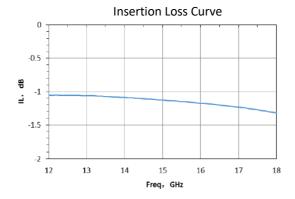
#### **Electrical Characteristics (Ta = 25°C)**

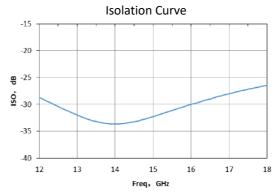
Symbol	Parameter	Test Conditions	Value			Unit
			Min	Typical	Max	
VSWR_in	Input Standing Wave	Pin = 0 dBm	-	1.4	1.6	
VSWR_out	Output Standing Wave		-	1.4	1.6	
IL	Insertion Loss	F : 12 ~ 18GHz	-	1.4	1.6	dB
ISO	Isolation		25	30	-	dB

## **Typical Performance**

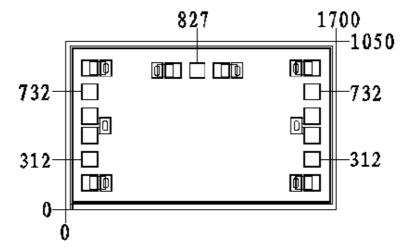




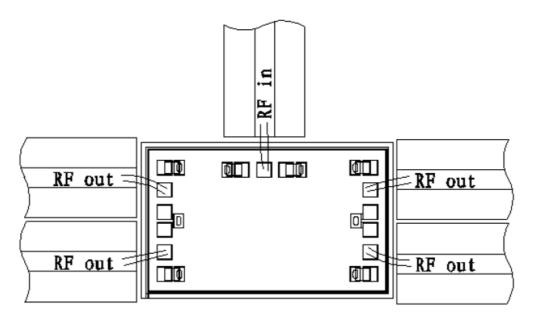




# Chip Dimensions (Unit: $\mu$ m)



# **Chip Layout Diagram**



Please see Appendix A for details.